

NCE3030K

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3030K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =30A

 $R_{DS(ON)}$ <14m Ω @ V_{GS} =10V

 $R_{DS(ON)}$ <25m Ω @ V_{GS} =4.5V

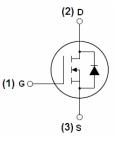
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

100% UIS TESTED!

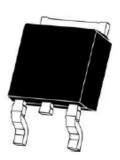
100% ΔVds TESTED!



Schematic diagram



Marking and pin Assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3030K	NCE3030K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	30	V	
Gate-Source Voltage	V _{GS}	±20	V	
Drain Current-Continuous	I _D	30	Α	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	21	Α	
Pulsed Drain Current	I _{DM}	80	Α	
Maximum Power Dissipation	P _D	40	W	
Derating factor		0.27	W/℃	
Single pulse avalanche energy (Note 5)	E _{AS}	72	mJ	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$	



NCE3030K

Thermal Characteristic

Electrical Characteristics (Tc=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•		•	•		•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA 30		-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	•		•	•		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.5	2.2	V
Danie Course On Otata Basistana	_	V _{GS} =10V, I _D =20A	-	10	14	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =15A	-	13	25	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	26	-	-	S
Dynamic Characteristics (Note4)	•		•	•		
Input Capacitance	C _{lss}	1/ 45)/// 0)/	-	938	-	PF
Output Capacitance	C _{oss}	V _{DS} =15V,V _{GS} =0V,	-	142	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	99	-	PF
Switching Characteristics (Note 4)	•		•	•		
Turn-on Delay Time	t _{d(on)}		-	5	-	nS
Turn-on Rise Time	t _r	V_{DD} =15V, R_L =0.75 Ω	-	12	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =3 Ω	-	19	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Q_g	\/ 45\/ L 00A	-	17.5		nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =20A,	-	3		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	4.1		nC
Drain-Source Diode Characteristics				Į.		•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	30	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =20A	-	19	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	10	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

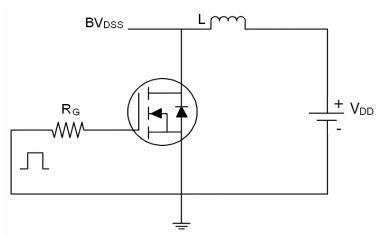
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=30V,V_G=10V,L=0.5mH,Rg=25 Ω

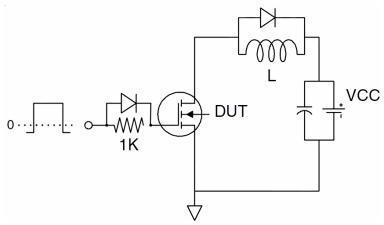


Test circuit

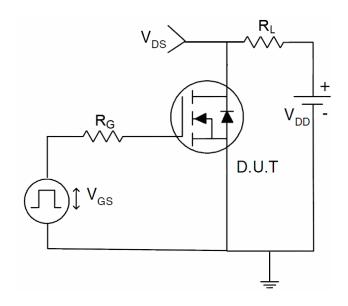
1) E_{AS} test Circuits



2) Gate charge test Circuit:



3) Switch Time Test Circuit:





Typical Electrical and Thermal Characteristics (Curves)

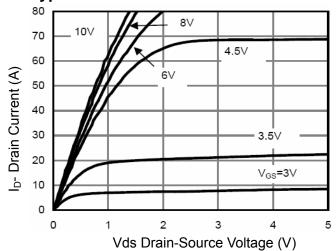


Figure 1 Output Characteristics

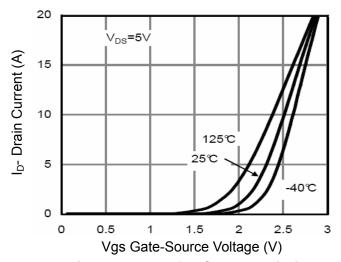


Figure 2 Transfer Characteristics

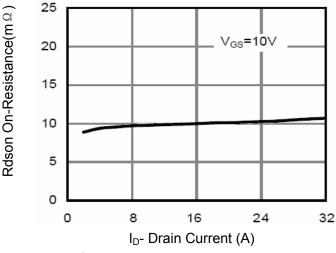


Figure 3 Rdson- Drain Current

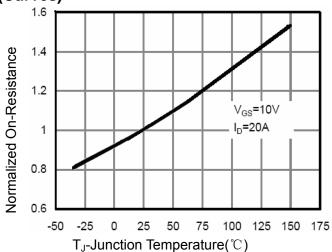


Figure 4 Rdson-Junction Temperature

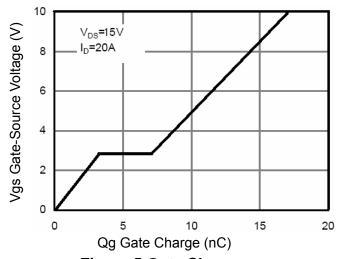


Figure 5 Gate Charge

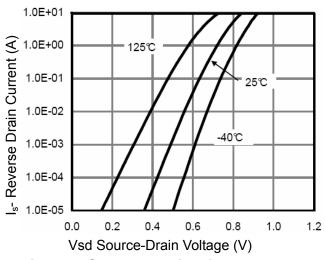


Figure 6 Source- Drain Diode Forward



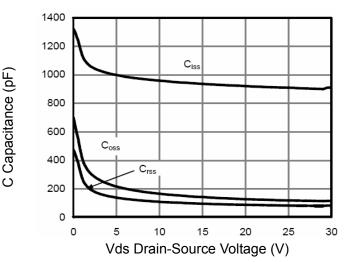


Figure 7 Capacitance vs Vds

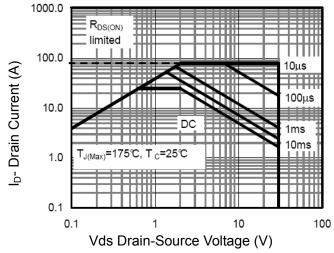


Figure 8 Safe Operation Area

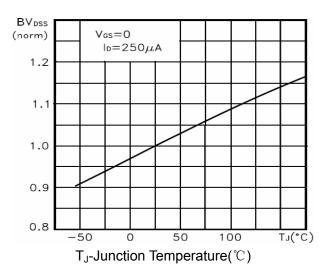


Figure 9 BV_{DSS} vs Junction Temperature

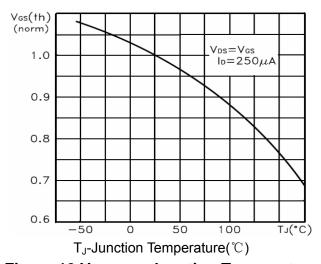


Figure 10 V_{GS(th)} vs Junction Temperature

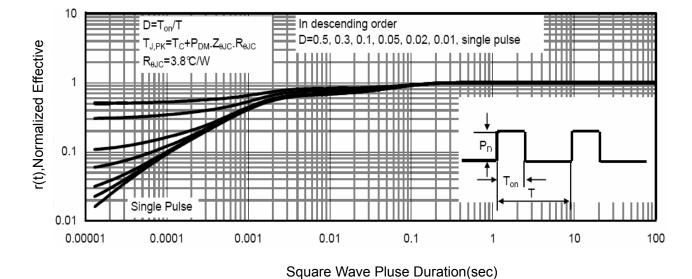
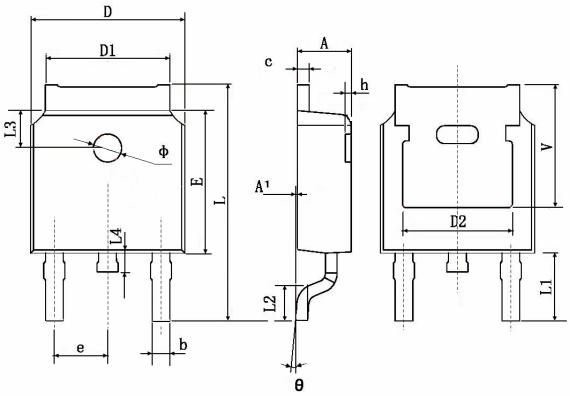


Figure 11 Normalized Maximum Transient Thermal Impedance



NCE3030K

TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	30TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP. 0.211 TYP.			TYP.	



http://www.ncepower.com

NCE3030K

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